

Features

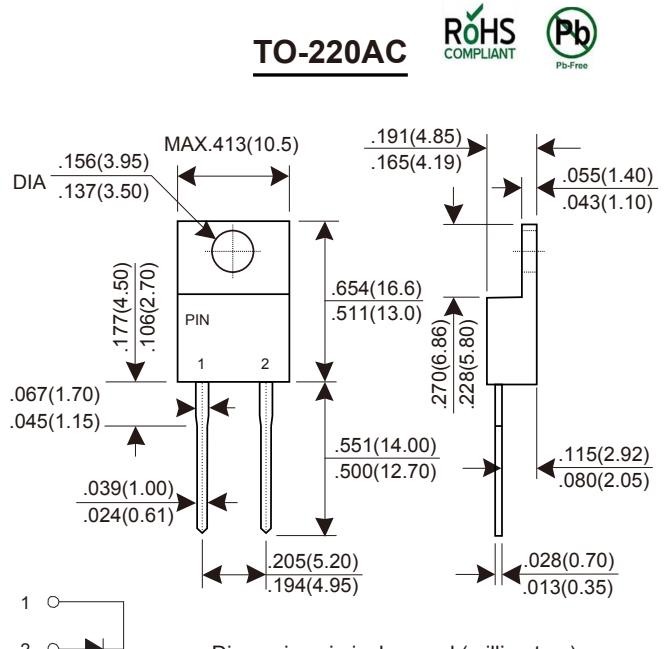
- High frequency operation
- High surge forward current capability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Mechanical Data

- **Package:** TO-220AC
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

Typical Applications

- Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.



Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MUR1020	MUR1040	MUR1060
Device marking code			MUR1020	MUR1040	MUR1060
Repetitive Peak Reverse Voltage	VRRM	V	200	400	600
Average Rectified Output Current @60Hz half sine-wave, R-load, Tc (FIG.1)	Io	A		10	
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Ta=25°C	IFSM	A		125	
Current Squared Time @1ms≤t<8.3ms Tj=25°C	I ² t	A ² s		65	
Storage Temperature	Tstg	°C		-55 ~ +150	
Junction Temperature	Tj	°C		-55 ~ +150	

Electrical Characteristics (Ta =25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MUR1020	MUR1040	MUR1060
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=10.0A	0.975	1.25	1.5
Maximum DC reverse current at rated DC blocking voltage per diode	IRRM1	uA	VRM=VRRM Ta=25°C	10		
	IRRM2		VRM=VRRM Ta=125°C	500		
Reverse Recovery Time	Trr	ns	I _F =0.5A I _{RM} =1A I _{RR} =0.25A	50		

Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MUR1020	MUR1040	MUR1060
Thermal Resistance	Between junction and case	°C/W		2.0	

Ordering Information (Example)

PREFERRED P/N			UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MUR1020	MUR1040	MUR1060	Approximate 1.39	50	1000	5000	Tube

Characteristics Typical
